Electronic Supplementary Information for

Solvent-Free Synthesis of Cu₂ZnSnS₄ Nanocrystals: A Facile, Green, Up-scalable Route for Low Cost Photovoltaic Cells[†]

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Fig. S1. XPS spectrum for S 2p of the as-synthesized Cu_2ZnSnS_4 nanocrystals (NCs). Note that the as-synthesized CZTS NCs are free from the oxidized species such as sulfates.



Fig. S2. Characterizations of $Cu_2ZnSnSe_4$ NCs immediately after the synthesis and after being stored on a bench top for one year: (a) XRD patterns, (b) Raman spectra, and (c) XPS spectra for Se 2p.



Fig. S3. A diode analysis on the Cu₂ZnSnSe₄ solar cell: (a) a plot of dj/dV vs. V, where G_{sh} was extracted from the plateau value assuming that a linear shunt current predominates the diode current in the range of V < 0, (b) a plot of dV/dj vs. $1/(j - G_{sh}V)$, where R_s and n were evaluated from the y-intercept and the slope, respectively, in the high bias regime, and (c) a semi-logarithmic plot of $(j - G_{sh}V)$ vs. $V - jR_s$ for determination of n and j_0 . The ideality factor (n) is determined in part b and c, respectively. Note that both values are in good agreement, thus supporting the validity of this analysis.



Fig. S4. TEM cross sectional images of the $Cu_2ZnSnSe_4$ solar cell with low (a) and high (a) magnification.